20V 175°C P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV_{DSS}	$R_{DS(ON)\ Max}$	I_D T_A = +25°C
-20V	38mΩ @ V_{GS} = -4.5V	-5.6A
	52mΩ @ V_{GS} = -2.5V	-4.8A

Features and Benefits

- Rated to +175°C—Ideal for High Ambient Temperature Environments
- Low Input Capacitance
- Low On-Resistance
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**
- **PPAP Capable (Note 4)**

Description and Applications

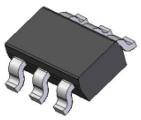
This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- DC-DC Converters
- Motor Control
- Power Management Functions
- Analog Switch

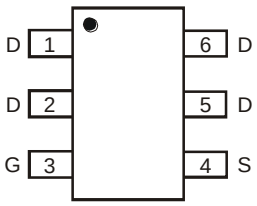
Mechanical Data

- Case: TSOT26
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish—Matte Tin Annealed over Copper Leadframe; Solderable per MIL-STD-202, Method 208 e3
- Weight: 0.013 grams (Approximate)

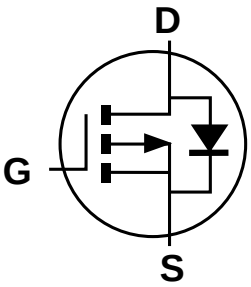
TSOT26



Top View



Top View
Pin-Out



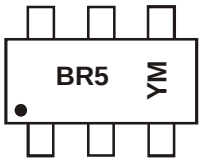
Equivalent Circuit

Ordering Information (Note 5)

Part Number	Case	Packaging
DMPH2040UVTQ-7	TSOT26	3,000/Tape & Reel
DMPH2040UVTQ-13	TSOT26	10,000/Tape & Reel

Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to https://www.diodes.com/quality/.
5. For packaging details, see https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



BR5 = Product Type Marking Code
YM = Date Code Marking
Y or $\overline{Y}$ = Year (ex: G = 2019)
M = Month (ex: 9 = September)

Date Code Key

Year	2019	2020	2021	2022	2023	2024	2025	2026	2027
Code	G	H	I	J	K	L	M	N	O

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

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Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V_{DSS}	-20	V
Gate-Source Voltage			V_{GSS}	±12	V
Continuous Drain Current (Note 7) V_{GS} = -4.5V	Steady State	T_A = +25°C T_A = +100°C	I_D	-5.6 -3.9	A
Continuous Drain Current (Note 8) V_{GS} = -4.5V	Steady State	T_C = +25°C T_C = +100°C	I_D	-11.7 -8.3	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			I_{DM}	-40	A
Continuous Source-Drain Diode Current (Note 7)			I_S	-2.0	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 6)	T_A = +25°C	P_D	1.0	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	$R_{\Theta JA}$	125	°C/W
Total Power Dissipation (Note 7)	T_A = +25°C	P_D	1.5	W
Thermal Resistance, Junction to Ambient (Note 7)	Steady State	$R_{\Theta JA}$	83	°C/W
Thermal Resistance, Junction to Case (Note 8)	Steady State	$R_{\Theta JC}$	19	°C/W
Operating and Storage Temperature Range		T_J, T_{STG}	-55 to +175	°C

Electrical Characteristics (T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 9)						
Drain-Source Breakdown Voltage	BV_{DSS}	-20	—	—	V	V_{GS} = 0V, I_D = -250µA
Zero Gate Voltage Drain Current	I_{DSS}	—	—	-1	µA	V_{DS} = -16V, V_{GS} = 0V
Gate-Source Leakage	I_{GSS}	—	—	±100	nA	V_{GS} = ±12V, V_{DS} = 0V
ON CHARACTERISTICS (Note 9)						
Gate Threshold Voltage	$V_{GS(TH)}$	-0.6	—	-1.5	V	V_{DS} = V_{GS}, I_D = -250µA
Static Drain-Source On-Resistance	$R_{DS(ON)}$	—	27	38	mΩ	V_{GS} = -4.5V, I_D = -8.9A
		—	38	52		V_{GS} = -2.5V, I_D = -6.9A
Diode Forward Voltage	V_{SD}	—	-0.7	-1.2	V	V_{GS} = 0V, I_S = -2.9A
DYNAMIC CHARACTERISTICS (Note 10)						
Input Capacitance	C_{iss}	—	834	—	pF	V_{DS} = -10V, V_{GS} = 0V, f = 1.0MHz
Output Capacitance	C_{oss}	—	133	—		
Reverse Transfer Capacitance	C_{rss}	—	105	—		
Gate Resistance	R_G	—	4.9	—	Ω	V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz
Total Gate Charge (V_{GS} = -4.5V)	Q_g	—	8.6	—	nC	V_{DS} = -6V, I_D = -8.9A
Total Gate Charge (V_{GS} = -8V)	Q_g	—	19	—		
Gate-Source Charge	Q_{gs}	—	1.5	—		
Gate-Drain Charge	Q_{gd}	—	2.5	—		
Turn-On Delay Time	$t_{D(ON)}$	—	5.8	—	ns	V_{DD} = -6V, R_L = 6Ω V_{GS} = -4.5V, R_G = 6Ω, I_D = -1A
Turn-On Rise Time	t_R	—	7.7	—		
Turn-Off Delay Time	$t_{D(OFF)}$	—	28.1	—		
Turn-Off Fall Time	t_F	—	14.6	—		
Body Diode Reverse Recovery Time	t_{RR}	—	9.8	—	ns	I_F = -8.9A, di/dt = -100A/µs
Body Diode Reverse Recovery Charge	Q_{RR}	—	2.7	—	nC	I_F = -8.9A, di/dt = -100A/µs

Notes:
6. Device mounted on FR-4 PCB, with minimum recommended pad layout, single sided.
7. Device mounted on FR-4 substrate PCB, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
8. Thermal resistance from junction to soldering point (on the exposed drain pad).
9. Short duration pulse test used to minimize self-heating effect.
10. Guaranteed by design. Not subject to product testing.

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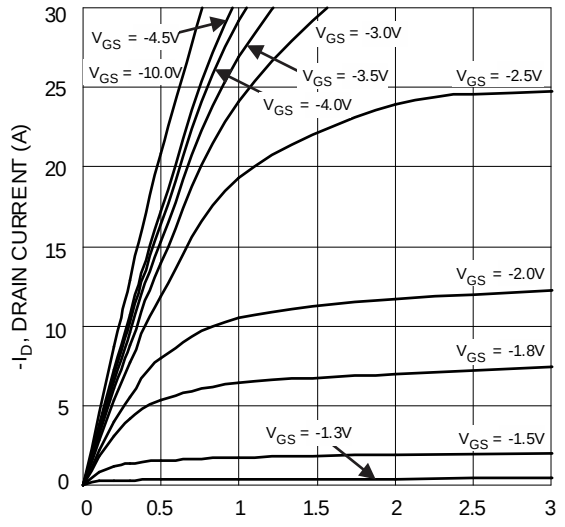


Figure 1 Typical Output Characteristics

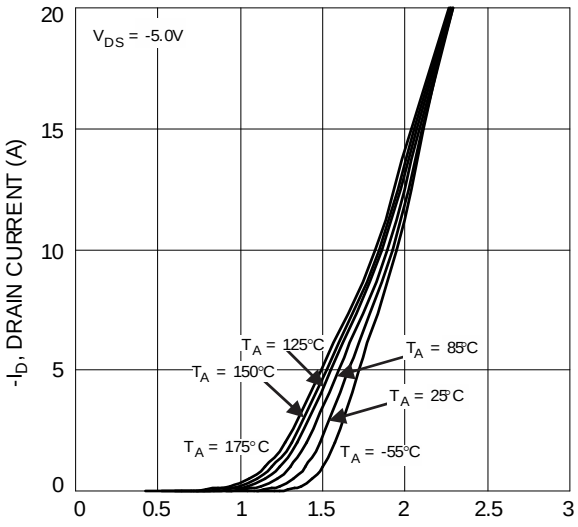


Figure 2 Typical Transfer Characteristics

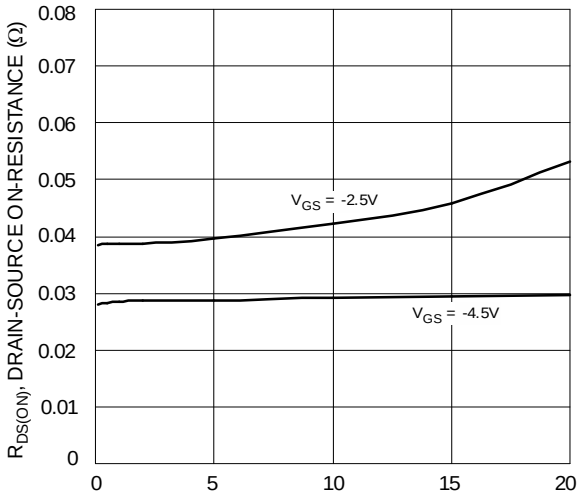


Figure 3 Typical On-Resistance vs.
Drain Current and Gate Voltage

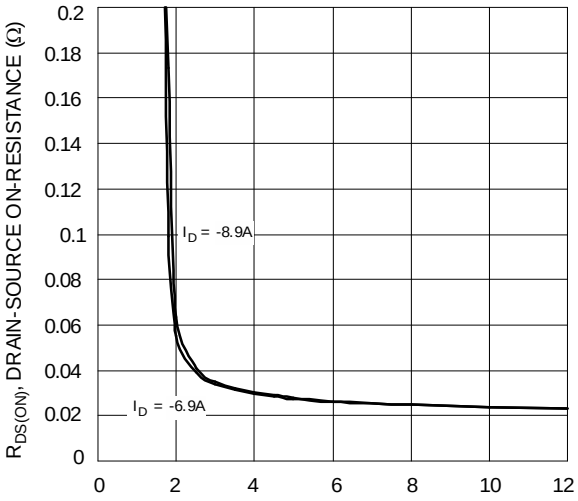


Figure 4 Typical Drain-Source On-Resistance
vs. Gate-Source Voltage

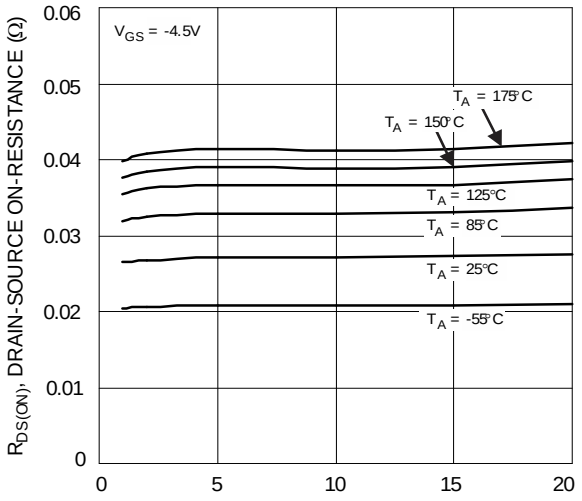


Figure 5 Typical On-Resistance vs.
Drain Current and Temperature

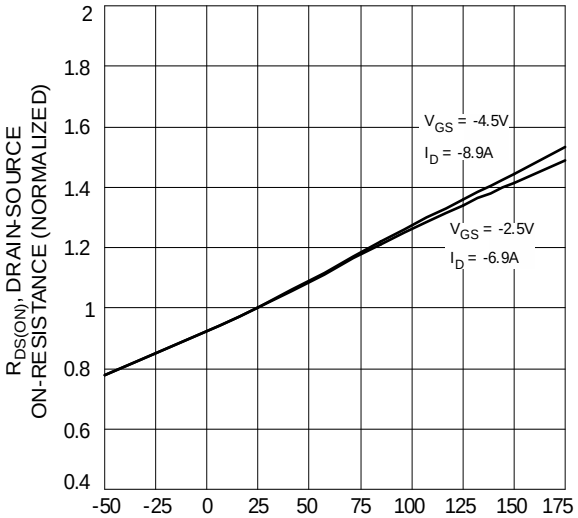


Figure 6 On-Resistance Variation with Temperature

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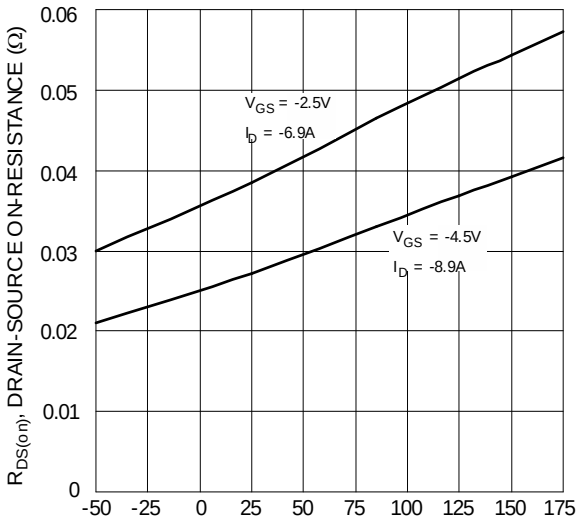


Figure 7 On-Resistance Variation with Temperature

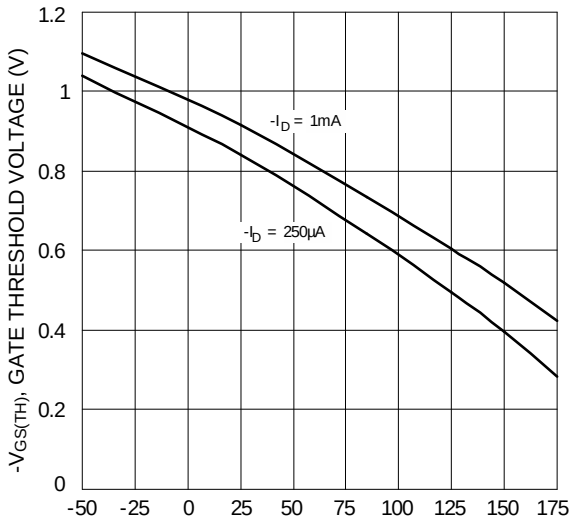


Figure 8 Gate Threshold Variation vs. Ambient Temperature

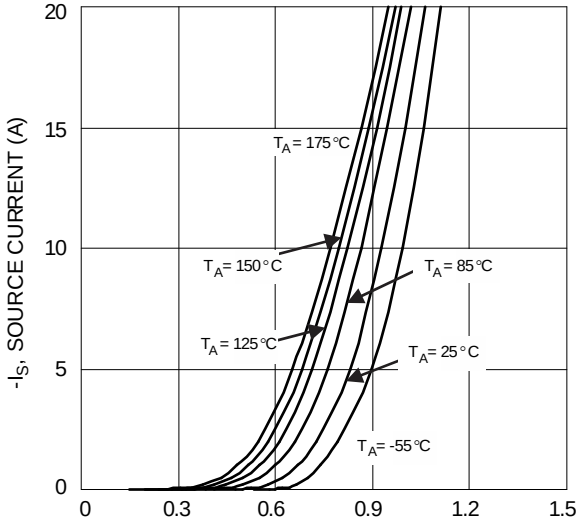


Figure 9 Diode Forward Voltage vs. Current

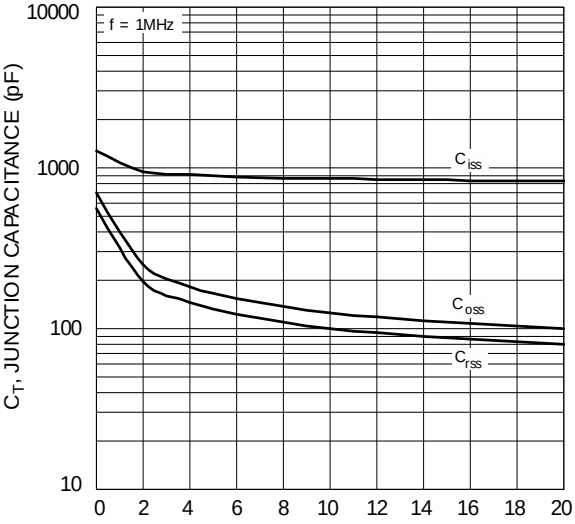


Figure 10 Typical Junction Capacitance

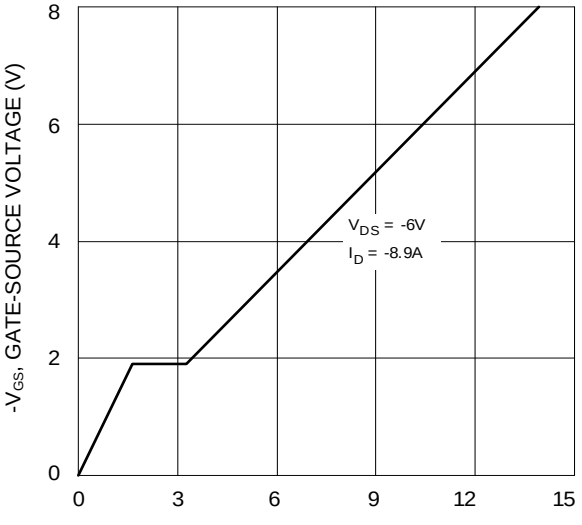


Figure 11 Gate Charge

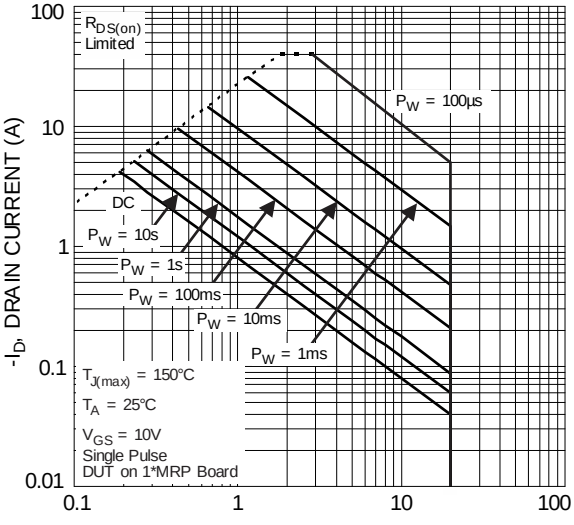


Figure 12 SOA, Safe Operation Area

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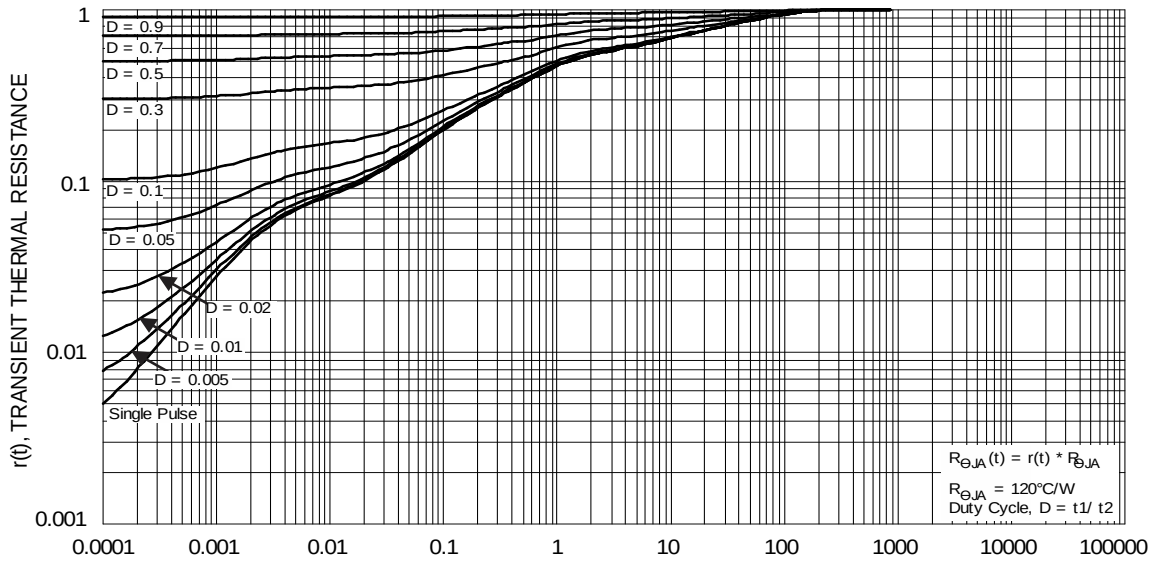


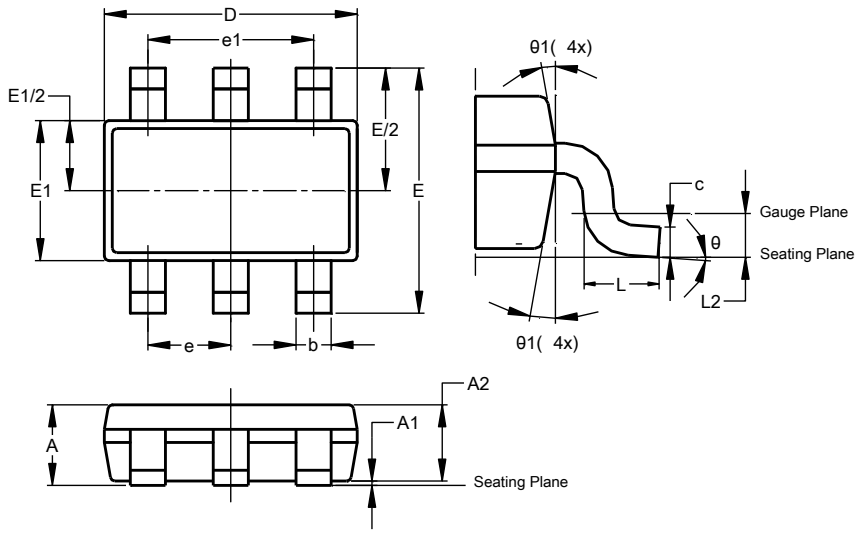
Figure 13 Transient Thermal Resistance

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Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

TSOT26

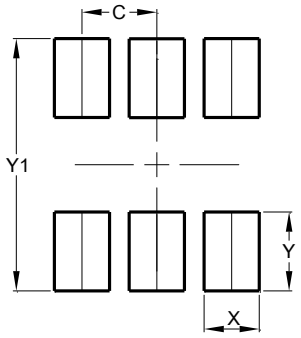


TSOT26			
Dim	**Min**	**Max**	**Typ**
A	—	1.00	—
A1	0.010	0.100	—
A2	0.840	0.900	—
D	2.800	3.000	2.900
E	2.800 BSC		
E1	1.500	1.700	1.600
b	0.300	0.450	—
c	0.120	0.200	—
e	0.950 BSC		
e1	1.900 BSC		
L	0.30	0.50	—
L2	0.250 BSC		
θ	0°	8°	4°
θ1	4°	12°	—
All Dimensions in mm			

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

TSOT26



Dimensions	Value (in mm)
C	0.950
X	0.700
Y	1.000
Y1	3.199

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